# **SA605**

# High performance low power mixer FM IF system Rev. 5 — 14 November 2014 Proc

**Product data sheet** 

#### **General description** 1.

The SA605 is a high performance monolithic low-power FM IF system incorporating a mixer/oscillator, two limiting intermediate frequency amplifiers, quadrature detector, muting, logarithmic received signal strength indicator (RSSI), and voltage regulator. The SA605 combines the functions of NXP SA602A and SA604A, but features a higher mixer input intercept point, higher IF bandwidth (25 MHz) and temperature compensated RSSI and limiters permitting higher performance application. The SA605 is available in 20-lead SO (surface-mounted miniature package) and 20-lead SSOP (shrink small outline package).

The SA605 and SA615 are functionally the same device types. The difference between the two devices lies in the guaranteed specifications. The SA615 has a higher I<sub>CC</sub>, lower input third-order intercept point, lower conversion mixer gain, lower limiter gain, lower AM rejection, lower SINAD, higher THD, and higher RSSI error than the SA605. Both the SA605 and SA615 devices meet the EIA specifications for AMPS and TACS cellular radio applications.

#### **Features and benefits** 2.

- Low power consumption: 5.7 mA typical at 6 V
- Mixer input to >500 MHz
- Mixer conversion power gain of 13 dB at 45 MHz
- Mixer noise figure of 4.6 dB at 45 MHz
- XTAL oscillator effective to 150 MHz (L/C oscillator to 1 GHz local oscillator can be injected)
- 102 dB of IF amplifier/limiter gain
- 25 MHz limiter small signal bandwidth
- Temperature-compensated logarithmic Received Signal Strength Indicator (RSSI) with a dynamic range in excess of 90 dB
- Two audio outputs muted and unmuted
- Low external component count; suitable for crystal/ceramic/LC filters
- Excellent sensitivity: 0.22 μV into 50 Ω matching network for 12 dB SINAD (Signal-to-Noise-and-Distortion ratio) for 1 kHz tone with RF at 45 MHz and IF at 455 kHz
- SA605 meets cellular radio specifications
- ESD hardened



## High performance low power mixer FM IF system

# 3. Applications

- Cellular radio FM IF
- High performance communications receivers
- Single conversion VHF/UHF receivers
- SCA receivers
- RF level meter
- Spectrum analyzer
- Instrumentation
- FSK and ASK data receivers
- Log amps
- Wideband low current amplification

# 4. Ordering information

Table 1. Ordering information

| Type number | Topside | Package |   |          |
|-------------|---------|---------|---|----------|
|             | marking | Name    | Description   | Version  |
| SA605D/01   | SA605D  | SO20    | plastic small outline package; 20 leads; body width 7.5 mm        | SOT163-1 |
| SA605DK/01  | SA605DK | SSOP20  | plastic shrink small outline package; 20 leads; body width 4.4 mm | SOT266-1 |

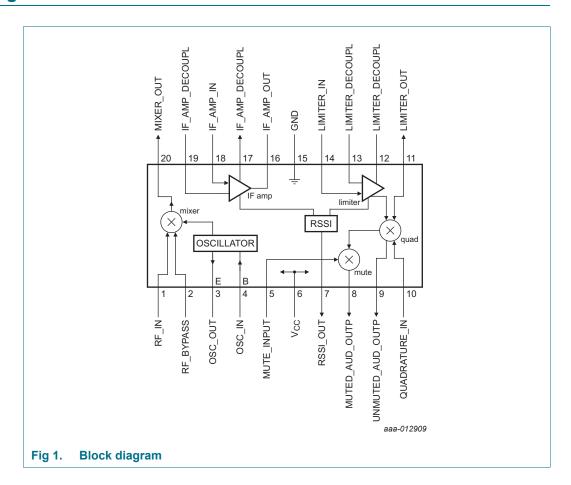
## 4.1 Ordering options

Table 2. Ordering options

| Type number | Orderable part number | Package | Minimum order quantity                       | Temperature |   |
|-------------|-----------------------|---------|--|-------------|---|
| SA605D/01   | SA605D/01,112         | SO20    | Standard marking * IC's tube - DSC bulk pack | 1520        | $T_{amb}$ = -40 °C to +85 °C  |
|             | SA605D/01,118         | SO20    | Reel 13" Q1/T1 *Standard mark SMD            | 2000        | $T_{amb}$ = -40 °C to +85 °C  |
| SA605DK/01  | SA605DK/01,112        | SSOP20  | Standard marking * IC's tube - DSC bulk pack | 1350        | $T_{amb} = -40  ^{\circ}\text{C} \text{ to } +85  ^{\circ}\text{C}$ |
|             | SA605DK/01,118        | SSOP20  | Reel 13" Q1/T1 *Standard mark SMD            | 2500        | $T_{amb}$ = -40 °C to +85 °C  |

## High performance low power mixer FM IF system

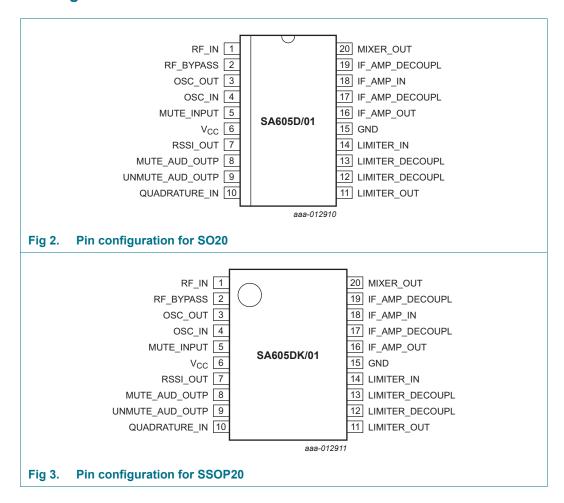
# 5. Block diagram



## High performance low power mixer FM IF system

# 6. Pinning information

#### 6.1 Pinning



## High performance low power mixer FM IF system

# 6.2 Pin description

Table 3. Pin description

| Symbol           | Pin | Description                        |
|------------------|-----|------------------------------------|
| RF_IN            | 1   | RF input                           |
| RF_BYPASS        | 2   | RF bypass pin                      |
| OSC_OUT          | 3   | oscillator output                  |
| OSC_IN           | 4   | oscillator input                   |
| MUTE_INPUT       | 5   | mute input                         |
| V <sub>CC</sub>  | 6   | positive supply voltage            |
| RSSI_OUT         | 7   | RSSI output                        |
| MUTED_AUD_OUTP   | 8   | mute audio output                  |
| UNMUTED_AUD_OUTP | 9   | unmute audio output                |
| QUADRATURE_IN    | 10  | quadrature detector input terminal |
| LIMITER_OUT      | 11  | limiter amplifier output           |
| LIMITER_DECOUPL  | 12  | limiter amplifier decoupling pin   |
| LIMITER_DECOUPL  | 13  | limiter amplifier decoupling pin   |
| LIMITER_IN       | 14  | limiter amplifier input            |
| GND              | 15  | ground; negative supply            |
| IF_AMP_OUT       | 16  | IF amplifier output                |
| IF_AMP_DECOUPL   | 17  | IF amplifier decoupling pin        |
| IF_AMP_IN        | 18  | IF amplifier input                 |
| IF_AMP_DECOUPL   | 19  | IF amplifier decoupling pin        |
| MIXER_OUT        | 20  | mixer output                       |

## High performance low power mixer FM IF system

# 7. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol           | Parameter           | Conditions | Min | Max  | Unit |
|------------------|---------------------|------------|-----|------|------|
| V <sub>CC</sub>  | supply voltage      |            | -   | 9    | V    |
| T <sub>stg</sub> | storage temperature |            | -65 | +150 | °C   |
| T <sub>amb</sub> | ambient temperature | operating  | -40 | +85  | °C   |

## 8. Thermal characteristics

#### Table 5. Thermal characteristics

| Symbol               | Parameter                | Conditions          | Тур | Unit |
|----------------------|--------------------------|---------------------|-----|------|
| Z <sub>th(j-a)</sub> |                          | SA605D/01 (SO20)    | 90  | K/W  |
|                      | from junction to ambient | SA605DK/01 (SSOP20) | 117 | K/W  |

## 9. Static characteristics

#### Table 6. Static characteristics

 $V_{CC}$  = +6 V;  $T_{amb}$  = 25 °C; unless specified otherwise.

| Symbol          | Parameter         | Conditions      | Min  | Тур | Max  | Unit |
|-----------------|-------------------|-----------------|------|-----|------|------|
| V <sub>CC</sub> | supply voltage    |                 | 4.5  | -   | 8.0  | V    |
| I <sub>CC</sub> | supply current    |                 | 4.55 | 5.7 | 6.55 | mA   |
| $V_{th}$        | threshold voltage | mute switch-on  | 1.7  | -   | -    | V    |
|                 |                   | mute switch-off | -    | -   | 1.0  | V    |

## High performance low power mixer FM IF system

# 10. Dynamic characteristics

#### Table 7. Dynamic characteristics

 $T_{amb} = 25$  °C;  $V_{CC} = +6$  V; unless specified otherwise. RF frequency = 45 MHz + 14.5 dBV RF input step-up. IF frequency = 455 kHz; R17 = 5.1 k $\Omega$ ; RF level = -45 dBm; FM modulation = 1 kHz with  $\pm 8$  kHz peak deviation. Audio output with C-message weighted filter and de-emphasis capacitor. Test circuit Figure 7. The parameters listed below are tested using automatic test equipment to assure consistent electrical characteristics. The limits do not represent the ultimate performance limits of the device. Use of an optimized RF layout improves many of the listed parameters.

| Symbol                 | Parameter Conditions                 |  | Min  | Тур  | Max | Unit |
|------------------------|--------------------------------------|--|------|------|-----|------|
| Mixer/oscil            | lator section (external LO = 300 m   | V)   |      |      |     |      |
| f <sub>i</sub>         | input frequency                      |  | -    | 500  | -   | MHz  |
| f <sub>osc</sub>       | oscillator frequency                 |  | -    | 150  | -   | MHz  |
| NF                     | noise figure                         | at 45 MHz  | -    | 5.0  | -   | dB   |
| IP3 <sub>i</sub>       | input third-order intercept point    | FL1 = 45.0 MHz; FL2 = 45.06 MHz  | -    | -10  | -   | dBm  |
| G <sub>p(conv)</sub>   | conversion power gain                | matched 14.5 dBV step-up   | 10   | 13   | 15  | dB   |
|                        |                                      | 50 Ω source  | -    | -1.7 | -   | dB   |
| R <sub>i(RF)</sub>     | RF input resistance                  | single-ended input   | 3.0  | 4.7  | -   | kΩ   |
| $C_{i(RF)}$            | RF input capacitance                 |  | -    | 3.5  | 4.0 | pF   |
| R <sub>o(mix)</sub>    | mixer output resistance              | MIXER_OUT pin  | 1.25 | 1.5  | -   | kΩ   |
| IF section             |                                      |  |      |      |     |      |
| G <sub>amp(IF)</sub>   | IF amplifier gain                    | 50 Ω source  | -    | 39.7 | -   | dB   |
| G <sub>lim</sub>       | limiter gain                         | 50 Ω source  | -    | 62.5 | -   | dB   |
| P <sub>i(IF)</sub>     | IF input power                       | for –3 dB input limiting sensitivity;<br>R17 = 5.1 kΩ; test at IF_AMP_IN pin | -    | -113 | -   | dBm  |
| $\alpha_{AM}$          | AM rejection                         | 80 % AM 1 kHz  | 29   | 34   | 43  | dB   |
|                        | audio level                          | RMS value; R10 = 100 k $\Omega$ ;<br>15 nF de-emphasis                       | 80   | 150  | 260 | mV   |
|                        | unmuted audio level                  | R11 = 100 k $\Omega$ ; 150 pF de-emphasis                                    | -    | 480  | -   | mV   |
| SINAD                  | signal-to-noise-and-distortion ratio | RF level –118 dB   | -    | 16   | -   | dB   |
| THD                    | total harmonic distortion            |  | -34  | -42  | -   | dB   |
| S/N                    | signal-to-noise ratio                | no modulation for noise  | -    | 73   | -   | dB   |
| V <sub>o(RSSI)</sub>   | RSSI output voltage                  | IF; R9 = 100 kΩ [1]  |      |      |     |      |
|                        |                                      | IF level = -118 dBm  | 0    | 160  | 650 | mV   |
|                        |                                      | IF level = -68 dBm   | 1.9  | 2.5  | 3.1 | V    |
|                        |                                      | IF level = -18 dBm   | 4.0  | 4.8  | 5.6 | V    |
| $\alpha_{RSSI(range)}$ | RSSI range                           | R9 = 100 kΩ; IF_AMP_OUT pin  | -    | 90   | -   | dB   |
| $\Delta \alpha_{RSSI}$ | RSSI variation                       | R9 = 100 kΩ; IF_AMP_OUT pin  | -    | ±1.5 | -   | dB   |
| $Z_{i(IF)}$            | IF input impedance                   |  | 1.40 | 1.6  | -   | kΩ   |
| $Z_{o(IF)}$            | IF output impedance                  |  | 0.85 | 1.0  | -   | kΩ   |
| $Z_{i(lim)}$           | limiter input impedance              |  | 1.40 | 1.6  | -   | kΩ   |
| R <sub>o</sub>         | output resistance                    | unmuted audio  | -    | 58   | -   | kΩ   |
|                        |                                      | muted audio  | -    | 58   | -   | kΩ   |

**SA605 NXP Semiconductors** 

## High performance low power mixer FM IF system

#### **Dynamic characteristics** ...continued

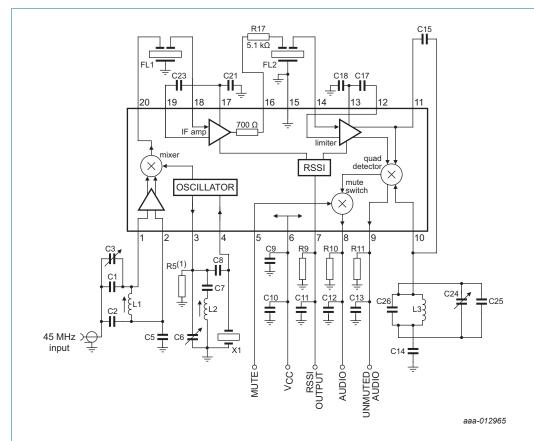
 $T_{amb}$  = 25 °C;  $V_{CC}$  = +6 V; unless specified otherwise. RF frequency = 45 MHz + 14.5 dBV RF input step-up. IF frequency = 455 kHz; R17 = 5.1 k $\Omega$ ; RF level = -45 dBm; FM modulation = 1 kHz with  $\pm$ 8 kHz peak deviation. Audio output with C-message weighted filter and de-emphasis capacitor. Test circuit Figure 7. The parameters listed below are tested using automatic test equipment to assure consistent electrical characteristics. The limits do not represent the ultimate performance limits of the device. Use of an optimized RF layout improves many of the listed parameters.

| Symbol               | Parameter           | arameter Conditions  |   |     |   |    |  |  |
|----------------------|---------------------|--|---|-----|---|----|--|--|
| RF/IF sect           | ion (internal LO)   |  |   |     | ' |    |  |  |
| unmuted audio level  |                     | vel RMS value; $V_{CC} = 4.5 \text{ V}$ ; RF level = $-27 \text{ dBm}$ |   | 450 | - | mV |  |  |
| V <sub>o(RSSI)</sub> | RSSI output voltage | system; $V_{CC}$ = 4.5 V;<br>RF level = -27 dBm                        | - | 4.3 | - | V  |  |  |

<sup>[1]</sup> The generator source impedance is 50  $\Omega$ , but the SA605 input impedance at pin 18 (IF\_AMP\_IN) is 1500  $\Omega$ . As a result, IF level refers to the actual signal that enters the SA605 input (pin 8, MUTED\_AUD\_OUTP) which is about 21 dB less than the 'available power' at the generator.

## High performance low power mixer FM IF system

# 11. Application information



The layout is very critical in the performance of the receiver. We highly recommend our demo board layout.

All of the inductors, the quad tank, and their shield must be grounded. A 10  $\mu$ F to 15  $\mu$ F or higher value tantalum capacitor on the supply line is essential. A low frequency ESR screening test on this capacitor ensures consistent good sensitivity in production. A 0.1  $\mu$ F bypass capacitor on the supply pin, and grounded near the 44.545 MHz oscillator improves sensitivity by 2 dB to 3 dB.

(1) R5 can be used to bias the oscillator transistor at a higher current for operation above 45 MHz. Recommended value is 22  $k\Omega$ , but should not be below 10  $k\Omega$ .

Fig 4. SA605 45 MHz application circuit

## High performance low power mixer FM IF system

Table 8. SA605 application component list

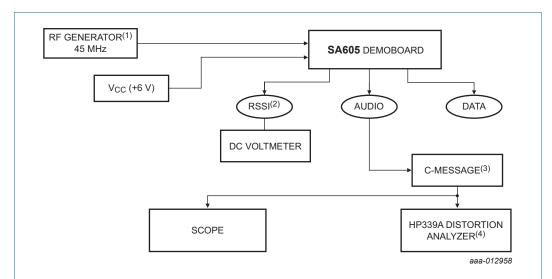
| Component               | Value                       | Description  | Package                      | Part number       |  |  |
|-------------------------|-----------------------------|--|------------------------------|-------------------|--|--|
| C1                      | 33 pF                       | NPO ceramic  | C0805K                       | 445-127x-1-ND     |  |  |
| C2                      | 220 pF                      | NPO ceramic  | C0805K                       | 445-7484-6-ND     |  |  |
| C3                      | 5 pF to 30 pF               | NPO ceramic; Murata TZC3P300A 110R00                 | TRIMCAP                      | 490-1994-2-ND     |  |  |
| C5                      | 100 nF ± 10 %               | 100 nF ± 10 % monolithic ceramic                     | C0805K                       | 311-1036-1-ND     |  |  |
| C6                      | 5 pF to 30 pF               | NPO ceramic; Murata TZC3P300A 110R00                 | TRIMCAP                      | 490-1994-2-ND     |  |  |
| C7                      | 1 nF                        | ceramic  | C0805K                       | 399-3293-1-ND     |  |  |
| C8                      | 10 pF                       | NPO ceramic  | C0805K                       | 490-1994-2-ND     |  |  |
| C9                      | 100 nF ± 10 %               | monolithic ceramic                                   | C0805K                       | 311-1036-1-ND     |  |  |
| C10[1]                  | 22 μF                       | tantalum   | C1812                        | 478-3117-1-ND     |  |  |
| C11                     | 100 nF ± 10 %               | monolithic ceramic                                   | C0805K                       | 311-1036-1-ND     |  |  |
| C12                     | 15 nF ± 10 %                | ceramic  | C0805K                       | 399-1161-1-ND     |  |  |
| C13                     | 150 pF $\pm$ 2 %            | N1500 ceramic  | C0805K                       | 399-1125-1-ND     |  |  |
| C14                     | 100 nF ± 10 %               | monolithic ceramic                                   | C0805K                       | 311-1036-1-ND     |  |  |
| C15                     | 10.0 pF                     | NPO ceramic  | C0805K                       | 311-1036-1-ND     |  |  |
| C17                     | 100 nF ± 10 %               | monolithic ceramic                                   | C0805K                       | 311-1036-1-ND     |  |  |
| C18                     | 100 nF ± 10 %               | monolithic ceramic                                   | C0805K                       | 311-1036-1-ND     |  |  |
| C21                     | 100 nF ± 10 %               | monolithic ceramic                                   | C0805K                       | 311-1036-1-ND     |  |  |
| C23                     | 100 nF ± 10 %               | monolithic ceramic                                   | C0805K                       | 311-1036-1-ND     |  |  |
| C24                     | 5 pF to 30 pF trim          | NPO ceramic; Murata TZC3P300A 110R00                 | TRIMCAP                      | 490-1994-2-ND     |  |  |
| C25                     | 470 pF                      | monolithic ceramic                                   | C0805K                       |                   |  |  |
| C26                     | 39 pF                       | monolithic ceramic                                   | C0805K                       |                   |  |  |
| CN1                     |                             | 8-pin header   | MA08-1                       | 399-8083-10ND     |  |  |
| CN2                     |                             | BU-SMA-H   | J502-ND-142-<br>0701-881/886 | 520-142-0701-881  |  |  |
| FL1, FL2 <sup>[2]</sup> |                             | ceramic filter;<br>Murata CFUKF455KB4X or equivalent | surface mount                | CFUKF455KB4X-R0   |  |  |
| L1                      | 330 nH                      | Coilcraft 1008CS-331                                 | WE-KI_1008_B                 | 1008CS-331        |  |  |
| L2                      | 1.2 μΗ                      | fixed inductor Coilcraft 1008CS-122XKLC              | WE-KI_1008_B                 | 1008CS-122        |  |  |
| L3                      | 220 μΗ                      | fixed inductor                                       | WE-GF_L                      | 1812LS-224XJB     |  |  |
| R9                      | 100 k $\Omega$ $\pm$ 1 %    | 1/4 W metal film                                     | R0603                        | 311-100KCRCT-ND   |  |  |
| R10[3]                  | 100 k $\Omega$ ± 1 %        | 1/4 W metal film                                     | C0805K                       | 311-100KCRCT-ND   |  |  |
| R11[3]                  | 100 k $\Omega$ ± 1 %        | 1/4 W metal film                                     | C0805K                       | 311-100KCRCT-ND   |  |  |
| R17                     | $5.1~\text{k}\Omega\pm5~\%$ | 1/4 W carbon composition                             | C0805K                       | 311-5.10KCRDKR-ND |  |  |
| U1                      |                             | SA605DK  | TSSOP20                      | 568-2087-5-nd     |  |  |
| X1                      | 44.545 MHz                  | resonant 3rd-overtone crystal                        | UM-1                         | 49HC/11453        |  |  |
|                         |                             |  |                              |                   |  |  |

<sup>[1]</sup> This value can be reduced when a battery is the power source.

<sup>[2]</sup> The ceramic filters can be 30 kHz SFG455A3s made by Murata, which have 30 kHz IF bandwidth (they come in blue), or 16 kHz CFU455Ds, also made by Murata (they come in black). All of our specifications and testing are done with the more wideband filter.

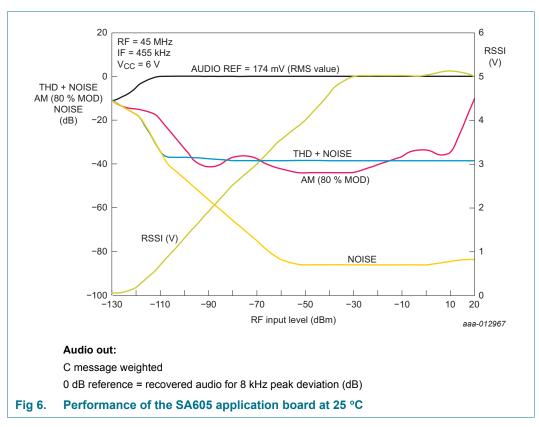
<sup>[3]</sup> Optional.

#### High performance low power mixer FM IF system



- (1) The C-message filter has a peak gain of 100 dB for accurate measurements. Without the gain, the measurements may be affected by the noise of the scope and HP339 analyzer.
- (2) Set your RF generator at 45.000 MHz, use a 1 kHz modulation frequency and a 6 kHz deviation if you use 16 kHz filters, or 8 kHz if you use 30 kHz filters.
- (3) The smallest RSSI voltage (that is, when no RF input is present and the input is terminated) is a measure of the quality of the layout and design. If the lowest RSSI voltage is 250 mV or higher, it means that the receiver is in regenerative mode. In that case, the receiver sensitivity is worse than expected.
- (4) The measured typical sensitivity for 12 dB SINAD should be 0.22  $\mu V$  or –120 dBm at the RF input.

Fig 5. SA605 application circuit test setup



#### High performance low power mixer FM IF system

## 11.1 Circuit description

The SA605 is an IF signal processing system suitable for second IF or single conversion systems with input frequency as high as 1 GHz. The bandwidth of the IF amplifier is about 40 MHz, with 39.7 dB of gain from a 50  $\Omega$  source. The bandwidth of the limiter is about 28 MHz with about 62.5 dB of gain from a 50  $\Omega$  source. However, the gain/bandwidth distribution is optimized for 455 kHz, 1.5 k $\Omega$  source applications. The overall system is well-suited to battery operation as well as high-performance and high-quality products of all types.

The input stage is a Gilbert cell mixer with oscillator. Typical mixer characteristics include a noise figure of 5 dB, conversion gain of 13 dB, and input third-order intercept of –10 dBm. The oscillator operates in excess of 1 GHz in L/C tank configurations. Hartley or Colpitts circuits can be used up to 100 MHz for crystal configurations. Butler oscillators are recommended for crystal configurations up to 150 MHz.

The output of the mixer is internally loaded with a 1.5 k $\Omega$  resistor, permitting direct connection to a 455 kHz ceramic filter. The input resistance of the limiting IF amplifiers is also 1.5 k $\Omega$ . With most 455 kHz ceramic filters and many crystal filters, no impedance matching network is necessary. To achieve optimum linearity of the log signal strength indicator, there must be a 12 dBV insertion loss between the first and second IF stages. If the IF filter or inter-stage network does not cause 12 dBV insertion loss, a fixed or variable resistor can be added between the first IF output (pin 16, IF\_AMP\_OUT) and the inter-stage network.

The signal from the second limiting amplifier goes to a Gilbert cell quadrature detector. One port of the Gilbert cell is internally driven by the IF. The other output of the IF is AC-coupled to a tuned quadrature network. This signal, which now has a 90° phase relationship to the internal signal, drives the other port of the multiplier cell.

Overall, the IF section has a gain of 90 dB. For operation at intermediate frequencies greater than 455 kHz, special care must be given to layout, termination, and inter-stage loss to avoid instability.

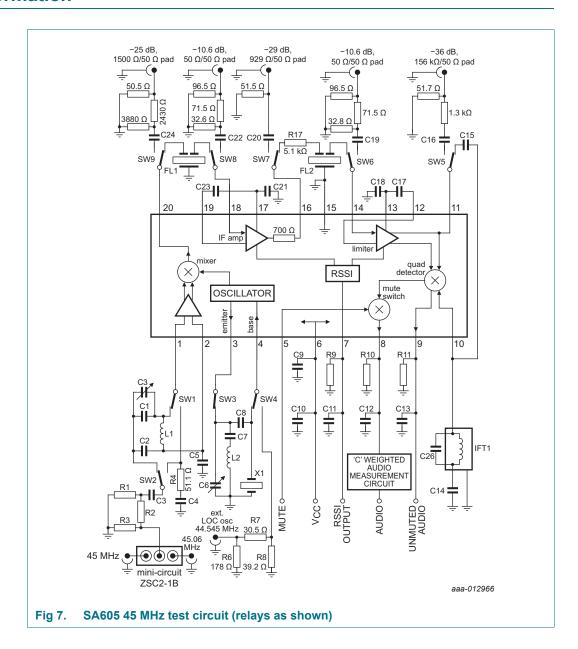
The demodulated output of the quadrature detector is available at two pins, one continuous and one with a mute switch. Signal attenuation with the mute activated is greater than 60 dB. The mute input is very high-impedance and is compatible with CMOS or TTL levels.

A log signal strength completes the circuitry. The output range is greater than 90 dB and is temperature compensated. This log signal strength indicator exceeds the criteria for AMPS or TACS cellular telephone.

Remark: dBV = 20log V<sub>O</sub> / V<sub>I</sub>.

#### High performance low power mixer FM IF system

# 12. Test information



## High performance low power mixer FM IF system

Table 9. Automatic test circuit component list

| Component                               | Description  |
|---|--|
| C1                                      | 33 pF NPO ceramic  |
| C2                                      | 180 pF NPO ceramic   |
| C3, C6                                  | 5 pF to 30 pF variable capacitor; Murata TZC3P300A 110R00          |
| C5, C9, C11, C14, C17,<br>C18, C21, C23 | 100 nF $\pm$ 10 % monolithic ceramic                               |
| C7                                      | 1 nF ceramic   |
| C8, C15                                 | 10 pF NPO ceramic  |
| C10[1]                                  | 6.8 μF tantalum (minimum)  |
| C12                                     | 15 nF ± 10 % ceramic   |
| C13                                     | 150 pF ± 2 % N1500 ceramic   |
| C26                                     | 390 pF ± 10 % monolithic ceramic                                   |
| FL1                                     | ceramic filter Murata SFG455A3 or equivalent                       |
| FL2                                     |  |
| IFT1                                    | 330 μH variable shielded inductor, Toko 836AN-0129Z                |
| L1                                      | 330 nH Coilcraft 1008CS-331  |
| L2                                      | 1.2 μH Coilcraft 1008CS-122  |
| X1                                      | 44.545 MHz 3rd Overtone series resonant crystal in the HC-49U case |
| R9                                      | 100 k $\Omega$ ± 1 % 1/4 W metal film                              |
| R10, R11                                | 100 k $\Omega$ ± 1 % 1/4 W metal film (optional)                   |
| R17                                     | 5.1 k $\Omega$ ± 5 % 1/4 W carbon composition                      |

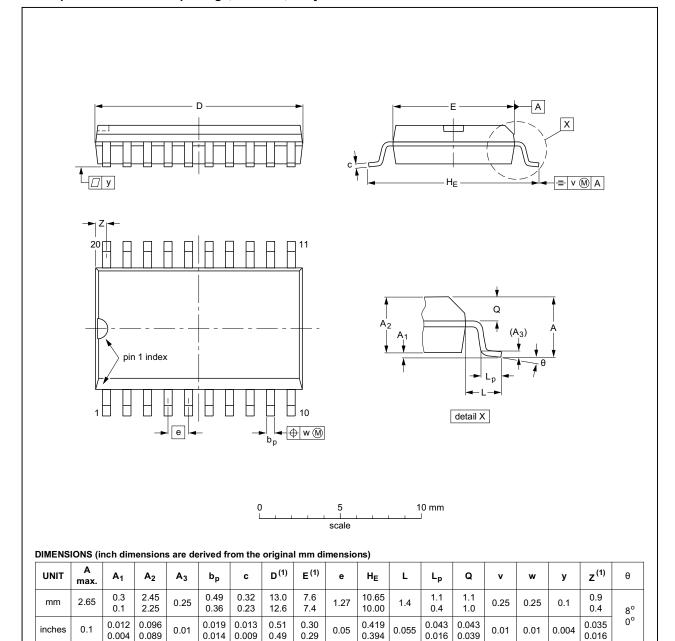
<sup>[1]</sup> This value can be reduced when a battery is the power source.

## High performance low power mixer FM IF system

# 13. Package outline

SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1



#### Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

| DEC  | JEITA |      | PROJECTION | ISSUE DATE                      |
|------|-------|------|------------|---------------------------------|
|      |       |      |            |                                 |
| -013 |       |      |            | <del>99-12-27</del><br>03-02-19 |
|      | -013  | -013 | 013        | 013                             |

Fig 8. Package outline SOT163-1 (SO20)

All information provided in this document is subject to legal disclaimers.

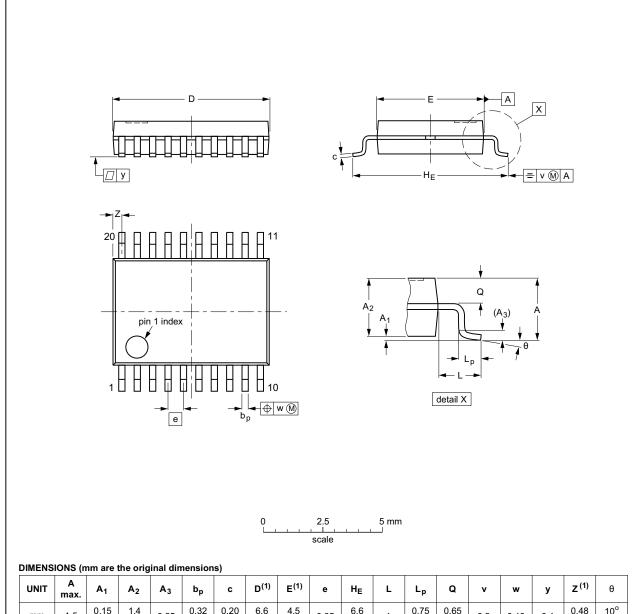
© NXP Semiconductors N.V. 2014. All rights reserved

**SA605 NXP Semiconductors** 

### High performance low power mixer FM IF system

### SSOP20: plastic shrink small outline package; 20 leads; body width 4.4 mm

SOT266-1



| UNIT | A<br>max. | A <sub>1</sub> | A <sub>2</sub> | <b>A</b> <sub>3</sub> | bp           | С            | D <sup>(1)</sup> | E <sup>(1)</sup> | е    | HE         | L | Lp           | Q            | v   | w    | у   | Z <sup>(1)</sup> | θ         |
|------|-----------|----------------|----------------|-----------------------|--------------|--------------|------------------|------------------|------|------------|---|--------------|--------------|-----|------|-----|------------------|-----------|
| mm   | 1.5       | 0.15<br>0      | 1.4<br>1.2     | 0.25                  | 0.32<br>0.20 | 0.20<br>0.13 | 6.6<br>6.4       | 4.5<br>4.3       | 0.65 | 6.6<br>6.2 | 1 | 0.75<br>0.45 | 0.65<br>0.45 | 0.2 | 0.13 | 0.1 | 0.48<br>0.18     | 10°<br>0° |

#### Note

1. Plastic or metal protrusions of 0.20 mm maximum per side are not included.

| OUTLINE  | REFERENCES |        |       | EUROPEAN | ISSUE DATE |                                 |
|----------|------------|--------|-------|----------|------------|---------------------------------|
| VERSION  | IEC        | JEDEC  | JEITA |          | PROJECTION | CTION ISSUE DATE                |
| SOT266-1 |            | MO-152 |       |          |            | <del>99-12-27</del><br>03-02-19 |

Fig 9. Package outline SOT266-1 (SSOP20)

All information provided in this document is subject to legal disclaimers.

© NXP Semiconductors N.V. 2014. All rights reserved.

## High performance low power mixer FM IF system

## 14. Soldering of SMD packages

This text provides a very brief insight into a complex technology. A more in-depth account of soldering ICs can be found in Application Note *AN10365 "Surface mount reflow soldering description"*.

#### 14.1 Introduction to soldering

Soldering is one of the most common methods through which packages are attached to Printed Circuit Boards (PCBs), to form electrical circuits. The soldered joint provides both the mechanical and the electrical connection. There is no single soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and Surface Mount Devices (SMDs) are mixed on one printed wiring board; however, it is not suitable for fine pitch SMDs. Reflow soldering is ideal for the small pitches and high densities that come with increased miniaturization.

#### 14.2 Wave and reflow soldering

Wave soldering is a joining technology in which the joints are made by solder coming from a standing wave of liquid solder. The wave soldering process is suitable for the following:

- Through-hole components
- · Leaded or leadless SMDs, which are glued to the surface of the printed circuit board

Not all SMDs can be wave soldered. Packages with solder balls, and some leadless packages which have solder lands underneath the body, cannot be wave soldered. Also, leaded SMDs with leads having a pitch smaller than ~0.6 mm cannot be wave soldered, due to an increased probability of bridging.

The reflow soldering process involves applying solder paste to a board, followed by component placement and exposure to a temperature profile. Leaded packages, packages with solder balls, and leadless packages are all reflow solderable.

Key characteristics in both wave and reflow soldering are:

- · Board specifications, including the board finish, solder masks and vias
- · Package footprints, including solder thieves and orientation
- The moisture sensitivity level of the packages
- Package placement
- · Inspection and repair
- Lead-free soldering versus SnPb soldering

#### 14.3 Wave soldering

Key characteristics in wave soldering are:

- Process issues, such as application of adhesive and flux, clinching of leads, board transport, the solder wave parameters, and the time during which components are exposed to the wave
- Solder bath specifications, including temperature and impurities

## High performance low power mixer FM IF system

## 14.4 Reflow soldering

Key characteristics in reflow soldering are:

- Lead-free versus SnPb soldering; note that a lead-free reflow process usually leads to higher minimum peak temperatures (see <u>Figure 10</u>) than a SnPb process, thus reducing the process window
- Solder paste printing issues including smearing, release, and adjusting the process window for a mix of large and small components on one board
- Reflow temperature profile; this profile includes preheat, reflow (in which the board is heated to the peak temperature) and cooling down. It is imperative that the peak temperature is high enough for the solder to make reliable solder joints (a solder paste characteristic). In addition, the peak temperature must be low enough that the packages and/or boards are not damaged. The peak temperature of the package depends on package thickness and volume and is classified in accordance with Table 10 and 11

Table 10. SnPb eutectic process (from J-STD-020D)

| Package thickness (mm) | Package reflow temperature (°C) |       |  |
|------------------------|---------------------------------|-------|--|
|                        | Volume (mm³)                    |       |  |
|                        | < 350                           | ≥ 350 |  |
| < 2.5                  | 235                             | 220   |  |
| ≥ 2.5                  | 220                             | 220   |  |

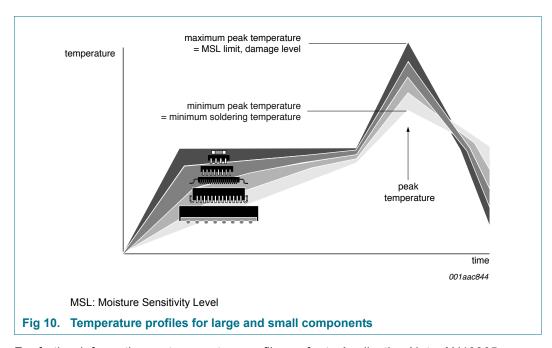
Table 11. Lead-free process (from J-STD-020D)

| Package thickness (mm) | Package reflow temperature (°C)  Volume (mm³) |             |        |  |
|------------------------|---|-------------|--------|--|
|                        |   |             |        |  |
|                        | < 350   | 350 to 2000 | > 2000 |  |
| < 1.6                  | 260   | 260         | 260    |  |
| 1.6 to 2.5             | 260   | 250         | 245    |  |
| > 2.5                  | 250   | 245         | 245    |  |

Moisture sensitivity precautions, as indicated on the packing, must be respected at all times.

Studies have shown that small packages reach higher temperatures during reflow soldering, see Figure 10.

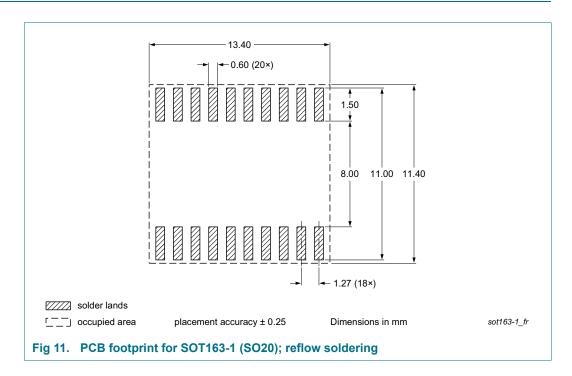
## High performance low power mixer FM IF system

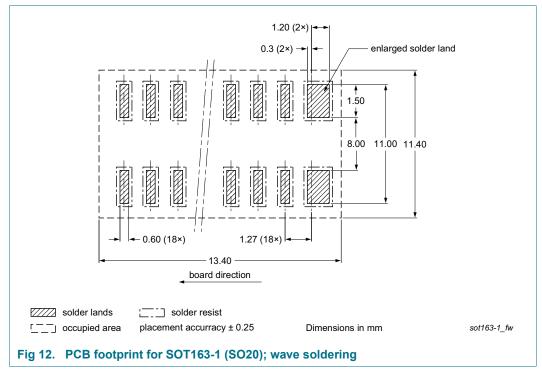


For further information on temperature profiles, refer to Application Note *AN10365* "Surface mount reflow soldering description".

#### High performance low power mixer FM IF system

# 15. Soldering: PCB footprints





### High performance low power mixer FM IF system

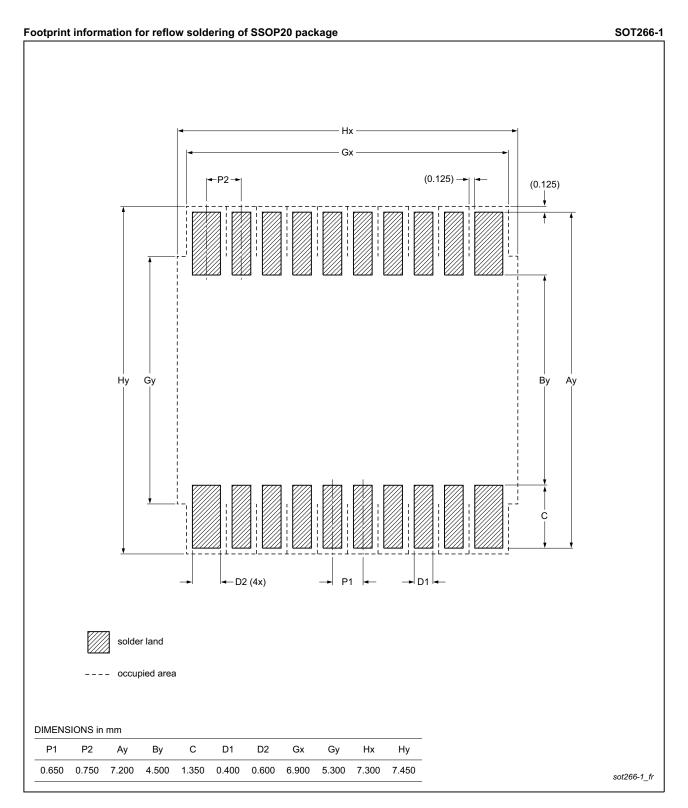


Fig 13. PCB footprint for SOT266-1 (SSOP20); reflow soldering

## High performance low power mixer FM IF system

# 16. Abbreviations

Table 12. Abbreviations

| Acronym | Description                             |
|---------|---|
| AM      | Amplitude Modulation                    |
| AMPS    | Advanced Mobile Phone System            |
| ASK     | Amplitude Shift Keying                  |
| CMOS    | Complementary Metal-Oxide Semiconductor |
| ESD     | ElectroStatic Discharge                 |
| ESR     | Equivalent Series Resistor              |
| FM      | Frequency Modulation                    |
| FSK     | Frequency Shift Keying                  |
| IF      | Intermediate Frequency                  |
| L/C     | inductor-capacitor filter               |
| RF      | Radio Frequency                         |
| RSSI    | Received Signal Strength Indicator      |
| SCA     | Subsidiary Communications Authorization |
| SINAD   | Signal-to-Noise-And-Distortion ratio    |
| TACS    | Total Access Communication System       |
| THD     | Total Harmonic Distortion               |
| UHF     | Ultra High Frequency                    |
| TTL     | Transistor-Transistor Logic             |
| VHF     | Very High Frequency                     |

# 17. Revision history

Table 13. Revision history

| Document ID    | Release date | Data sheet status   | Change notice      | Supersedes |
|----------------|--------------|---|--------------------|------------|
| SA605 v.5      | 20141114     | Product data sheet  | -                  | SA605 v.4  |
| Modifications: |              | application component list" update 5 45 MHz application circuit" update |                    |            |
| SA605 v.4      | 20140801     | Product data sheet  | -                  | SA605 v.3  |
| SA605 v.3      | 20140501     | Product data sheet  | -                  | SA605 v.2  |
| SA605 v.2      | 19971107     | Product specification   | ECN 853-1401 18663 | SA605 v.1  |
| SA605 v.1      | 19921103     | Product specification   | -                  | -          |

#### High performance low power mixer FM IF system

## 18. Legal information

#### 18.1 Data sheet status

| Document status[1][2]          | Product status[3] | Definition  |
|--------------------------------|-------------------|---|
| Objective [short] data sheet   | Development       | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification     | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production        | This document contains the product specification.                                     |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

#### 18.2 Definitions

**Draft** — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

**Product specification** — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

#### 18.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. NXP Semiconductors takes no responsibility for the content in this document if provided by an information source outside of NXP Semiconductors.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors and its suppliers accept no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at <a href="http://www.nxp.com/profile/terms">http://www.nxp.com/profile/terms</a>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

**No offer to sell or license** — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

SA605

All information provided in this document is subject to legal disclaimers.

© NXP Semiconductors N.V. 2014. All rights reserved.

#### High performance low power mixer FM IF system

**Export control** — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Non-automotive qualified products — Unless this data sheet expressly states that this specific NXP Semiconductors product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. NXP Semiconductors accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without NXP Semiconductors' warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond

NXP Semiconductors' specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies NXP Semiconductors for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond NXP Semiconductors' standard warranty and NXP Semiconductors' product specifications.

**Translations** — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

#### 18.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

## 19. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com

**SA605 NXP Semiconductors** 

## High performance low power mixer FM IF system

# 20. Contents

| 1    | General description       | . 1 |
|------|---------------------------|-----|
| 2    | Features and benefits     | . 1 |
| 3    | Applications              | . 2 |
| 4    | Ordering information      | . 2 |
| 4.1  | Ordering options          | . 2 |
| 5    | Block diagram             |     |
| 6    | Pinning information       |     |
| 6.1  | Pinning                   |     |
| 6.2  | Pin description           |     |
| 7    | Limiting values           |     |
| 8    | Thermal characteristics   |     |
| 9    | Static characteristics    |     |
| 10   | Dynamic characteristics   |     |
| 11   | Application information   |     |
| 11.1 | Circuit description       |     |
| 12   | Test information          |     |
| 13   | Package outline           |     |
| 14   | Soldering of SMD packages |     |
| 14.1 |                           | 17  |
| 14.1 | Introduction to soldering | 17  |
| 14.2 | Wave and reflow soldering | 17  |
| 14.3 | Wave soldering            | 18  |
| 15   | _                         |     |
| . •  | Soldering: PCB footprints |     |
| 16   | Abbreviations             |     |
| 17   | Revision history          |     |
| 18   | Legal information         | 23  |
| 18.1 | Data sheet status         | 23  |
| 18.2 | Definitions               | 23  |
| 18.3 | Disclaimers               | 23  |
| 18.4 | Trademarks                |     |
| 19   | Contact information       | 24  |
| 20   | Contents                  | 25  |

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.